- Provides High-Voltage Differential SCSI From Single-Ended Controller When Used With the SN75970B Control Transceiver
- Meets or Exceeds the Requirements of EIA Standard RS-485 and ISO-8482 Standards
- ESD Protection on Bus Pins to 12 kV
- Packaged in Shrink Small-Outline Package with 25 mil Terminal Pitch and Thin Small-Package with 20 mil Terminal Pitch
- Low Disabled-Supply Current 32 mA Typ
- Thermal Shutdown Protection
- Positive- and Negative-Current Limiting
- Power-Up/-Down Glitch Protection
- Open-Circuit Failsafe Receivers

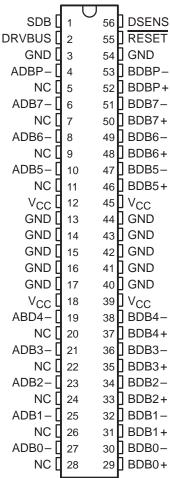
description

The SN75971B SCSI differential converter-data is a 9-channel RS-485 transceiver. When used in conjunction with its companion control transceiver, the SN75970B, the resulting chip set provides the superior electrical performance of differential SCSI from a single-ended SCSI bus or controller. A 16-bit Ultra-SCSI (or Fast-20) SCSI bus can be implemented with just three devices (two data and one control) in the space efficient, 56-pin, shrink small-outline package (SSOP) or thin shink small outline package (TSSOP) and a few external components. An 8-bit SCSI bus requires only one data and one control transceiver.

The SN75971B is available in a B2 (20 Mxfer) version and a B1 (10 Mxfer) version.

In a typical differential SCSI node, the SCSI controller provides an enable for each external RS-485 transceiver channel. This could require as many as 27

DGG OR DL PACKAGE (TOP VIEW)



Pins 13 – 17 and 40 – 44 are connected together to the package lead frame and to signal ground.

NC - No internal connection

extra terminals for a 16-bit differential bus controller or relegate a 16-bit, single-ended controller to only an 8-bit differential bus. Using the standard nine SCSIcontrol signals, the SN75970B control transceiver decodes the state of the bus and enables the SN75971B data transceiver to transmit the single-ended SCSI input signals (A side) differentially to the cable or receive the differential cable signals (B side) and drive the single-ended outputs to the controller.

A reset function, which disables all outputs and clears internal latches, can be accomplished from two external inputs and two internally-generated signals. RESET (reset) and DSENS (differential sense) are available to external circuits for a bus reset or to disable all outputs should a single-ended cable be inadvertently connected to a differential connector. Internally-generated power-up and thermal-shutdown signals have the same affect when the supply voltage is below approximately 3.5 V or the junction temperature exceeds 175°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



description (continued)

The SCSI, differential, converter-data chip operates in two modes depending on the state of the DRVBUS input. With DRVBUS low, a bidirectional latch circuit sets the direction of data transfer. Each data bit has its own latch, and each bit's direction is independent of all other bits. When neither the single-ended nor the differential sides are asserted, the latch disables both A- and B-side output drivers. When the input to either side is asserted, the latch enables the opposite side's driver and sets data flow from the asserted input to the opposite side of the device. When the input deasserts, the latch maintains the direction until the receiver on the enabled driver detects a deassertion. The latch then returns to the initial state. No parity checking is done by this device; the parity signal passes through the device like other data signals do.

When DRVBUS is high, direction is determined by the SDB signal. However, a change in SDB does not always immediately change the direction. When DRVBUS first asserts, the direction indicated by SDB is latched and takes effect immediately. When SDB changes while DRVBUS is high, the drivers that were on immediately turn off. However, the other driver set does not turn on until the receivers sense a deasserted state on all nine data lines. This is done to prevent the active drivers from turning on until all other drivers are off and the terminators pull the lines to a deasserted state.

The single-ended SCSI bus interface consists of CMOS, bidirectional inputs and outputs. The drivers are rated to ±16 mA of output current. The receiver inputs are pulled high with approximately 4 mA to eliminate the need for external pullup resistors for the open-drain outputs of most single-ended SCSI controllers. The single-ended side of the device is not intended to drive the SCSI bus directly.

The differential SCSI bus interface consists of bipolar, bidirectional inputs and outputs that meet or exceed the requirements of EIA-485 and ISO 8482-1982/TIA TR30.2 referenced by American National Standard of Information Systems (ANSI) X3.131-1994 Small Computer System Interface-2 (SCSI-2) and SCSI-3 Fast-20 Parallel Interface (Fast-20) X3,277:1996.

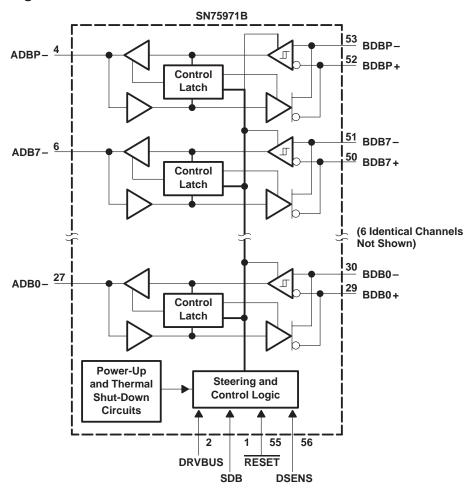
The SN75971B is characterized for operation over the temperature range of 0°C to 70°C.

Terminal Functions

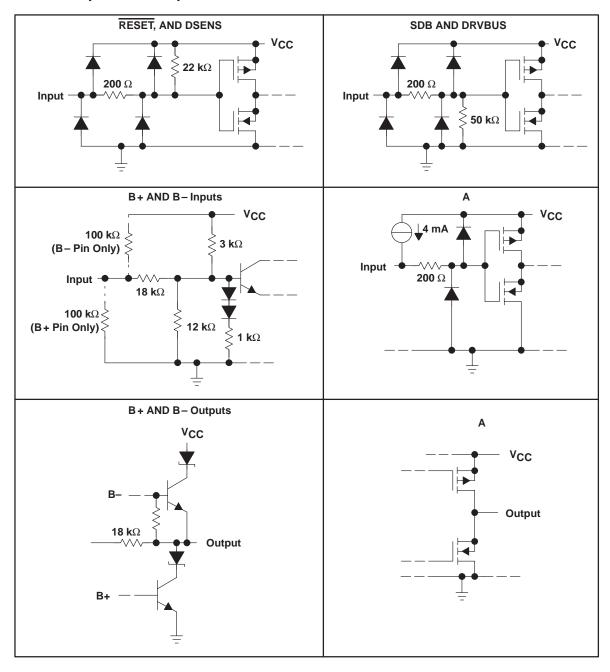
TERMINAL		1/0	DESCRIPTION				
NAME	NO.	I/O	DESCRIPTION				
ADBn-, where n = {0,1,2,3,4,5,6,7,P}	4, 6, 8, 10, 19, 21, 23, 25, 27	I/O, Single-ended SCSI voltage levels, Strong pullup	Bidirectional I/O for data and parity bits to and from the single-ended SCSI controller. As outputs, these terminals can source or sink 16 mA. As inputs, they are pulled up with about 4-mA to eliminate external resistors.				
BDBn+, where n = {0,1,2,3,4,5,6,7,P}	29, 31, 33, 35, 37, 46, 48, 50, 52	I/O, RS-485, Weak pulldown	Bidirectional I/O for data and parity to and from the differential SCSI bus.				
BDBn-, where n = {0,1,2,3,4,5,6,7,P}	30, 32, 34, 36, 38,47, 49, 51, 53	I/O, RS-485, Weak pulldown	Bidirectional I/O for the complement of data and parity to and from the differential SCSI bus.				
DRVBUS	2	Input, TTL levels, Weak pulldown	A high-level logic signal from the control transceiver enables either the single-ended or differential drivers as directed by SDB.				
DSENS	56	Input, TTL levels, Weak pullup	A low-level input initializes the internal latches and disables all drivers.				
RESET	55	Input, TTL levels, Weak pullup	A low-level input initializes the internal latches and disables all drivers.				
SDB	1	Input, TTL levels, Weak pulldown	A high-level logic signal from the control transceiver sends data from the differential bus to the single-ended bus. A low-level signal reverses the flow.				



functional block diagram



schematics of inputs and outputs





absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC} (see Note 1)0.3 V to 7 V
Differential bus voltage range (B side)
Single-ended bus voltage range (A side and control inputs)
Continuous total power dissipation (see Note 2) Internally Limited (see Dissipation Rating Table)
Electrostatic discharge (see Note 3): Class 2 A (all pins)
Class 2 B (all pins)
Class 3 A (B-side and GND)
Class 3 B (B-side and GND)
Operating free-air temperature range, T _A
Storage temperature range, T _{stg}
_ead temperature 1,6 mm (1/16 inch) from case for 10 seconds

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values are with respect to GND.

- 2. The maximum operating junction temperature is internally limited. Use the dissipation rating table to operate below this temperature.
- 3. This absolute maximum rating is tested in accordance with MIL-STD-883C, Method 3015.7.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR [‡] ABOVE T _A = 25°C	T _A = 70°C POWER RATING		
DGG	3333 mW	26.7 mW/°C	2133 mW		
DL	3709 mW	29.7 mW/°C	2374 mW		

[‡] This is the inverse of the traditional junction-to-case thermal resistance ($R_{\theta JA}$) for High-K (per JEDEC) PCB installations.

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage, V _{CC}				5.25	V
High-level input voltage, VIH	A side and control	2			V
Low-level input voltage, V _{IL}	A side and control			0.8	V
Voltage at any bus terminal (separately or common-mode), $V_{\mbox{\scriptsize O}}$ or $V_{\mbox{\scriptsize I}}$	B side			12 -7	V
High-level output current, I _{OH}	A side			-16	mA
Low-level output current, I _{OL}	A side			16	mA
Operating case temperature, T _C		0		125	°C
Operating free-air temperature, T _A				70	°C

SN75971B SCSI DIFFERENTIAL CONVERTER-DATA

SLLS322A - NOVEMBER 1999 - REVISED JANUARY 2000

electrical characteristics over recommended operating conditions (unless otherwise noted)

PARAMETER			TEST CONDITIONS			TYP [†]	MAX	UNIT
VOD(H)	Driver high-level differenti	al output voltage	See Figure 1		-1	-2.2		V
V _{OD(L)}	Driver low-level differentia	l output voltage	See Figure 1		1	1.8		V
	High-level output	A side	$V_{ID} = -200 \text{ mV},$	$I_{OH} = -16 \text{ mA}$	2.5	4.2		V
VOH	voltage	B side	$I_{OH} = -60 \text{ mA}$			3.4		V
V	Low level cutout valtage	A side	V _{ID} = 200 mV,	I _{OL} = 16 mA		0.4	0.8	V
VOL	Low-level output voltage	B side	I _{OL} = 60 mA			1.6		V
V _{IT+}	Receiver positive-going differential input threshold voltage		I _{OH} = -16 mA	See Figure 2			0.2	V
V _{IT} —	Receiver negative-going differential input threshold voltage	B side	I _{OL} = 16 mA	See Figure 2	-0.2§			V
V _{hys}	Receiver input hysteresis voltage (V _{IT+} - V _{IT-})				35	45		mV
	Bus input current	B or B	V _I = 12 V, Other input at 0 V	$V_{CC} = 5 V$		0.6	1	mA
l _{ti}				$V_{CC} = 0$		0.7	1	ША
["			$V_I = -7 \text{ V}$, Other input at 0 V	V _{CC} = 5 V		-0.5	-0.8	mA
			V = 7 V, Other input at 0 V	ACC = 0		-0.4	-0.8	111/-
	High-level input current	A side	V _{IH} = 2 V			-5	-8	mA
lН		RESET, DSENS				-70	-100	μΑ
		SDB, DRVBUS					25	μπ
	Low-level input current	A side				-6	-9	mA
Iμ		RESET, DSENS	V _{IL} = 0.8 V			-66	-100	μΑ
		SDB, DRVBUS					±30	μΛ
los	Short-circuit output current	B side	V _O = 5 V and 0				±250	mA
	High impedance state	A side			-2	-5	-8	
loz	High-impedance-state output current	7 olde				-6	-9	
		B side				See I _I		
	Supply current	Disabled	RESET at 0.8 V,	Others open		38	46	
^I CC		B to A Enabled	SDB and DRVBUS at 2 V, All other inputs open,	V _{ID} = −1 V, No load		39	50	mA
		A to B Enabled	SDB at 0.8 V, All other inputs open,	DRVBUS at 2 V, No load		32	66	
CO	Output capacitance		$V_I = 0.6 \sin(2\pi \times 10^6 t) + 1.5 V$	BDBn to GND		18	21	pF
Const	Power dissination canceit	anceİ	B to A,	One channel		40		pF
⊃pa	C _{pd} Power dissipation capacitance [‡]		A to B,	One channel		100		pF



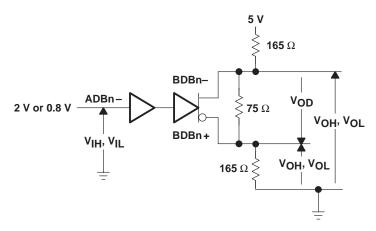
[†] All typical values are at V_{CC} = 5 V, T_A = 25°C.
‡ C_{pd} determines the no-load dynamic current consumption, I_S = C_{pd} × V_{CC} × f + I_{CC}.
§ The algebraic convention with the least positive (more negative) limit is designated minimum, is used in this data sheet for the differential input voltage only.

switching characteristics over recommended of operating conditions (unless otherwise noted)

PARAMETER			TEST CONDITIONS			MAX	UNIT	
	Delay time, A to B, high- to low- level or low- to high-level output	SN75971B1	See Figures	3	14			
			$V_{CC} = 5 V$	$T_A = 25$ °C, See Figures 3 and 4	4	12]	
			$V_{CC} = 5 V$	$T_A = 70^{\circ}C$, See Figures 3 and 4	4.9	12.9		
td1, td2			See Figures	See Figures 3 and 4			ns	
		SN75971B2	$V_{CC} = 5 V$	$T_A = 25^{\circ}C$, See Figures 3 and 4	6.2	10.2		
			$V_{CC} = 5 V$	$T_A = 70^{\circ}C$, See Figures 3 and 4	6.9	10.9		
			See Figures	5 and 6	5.4	18.1		
		SN75971B1	V _C C = 5 V,	T _A = 25°C, See Figures 5 and 6	6.5	15.4		
	Delay time, B to A, high- to low- level or low- to high-level output		V _C C = 5 V,	T _A = 70°C, See Figures 5 and 6	7.2	16.1		
td3, td4		SN75971B2	See Figures	See Figures 5 and 6			ns	
			V _C C = 5 V,	T _A = 25°C, See Figures 5 and 6	8.7	13.2		
			V _{CC} = 5 V,	T _A = 70°C, See Figures 5 and 6	9.4	13.9		
	Skew, part-to-part [†]	SN75971B1	A to B	See Figures 5 and 6		8	8	
.			B to A	See Figures 5 and 6		9	ns	
^t sk(pp)		SN75971B2	A to B	See Figures 5 and 6		4		
			B to A	See Figures 5 and 6		5		
t _{sk(p)}	Pulse skew [‡]					4	ns	
tdis1	Disable time, A to B		See Figures 3 and 4			200	ns	
t _{dis2}	Disable time, B to A		See Figures	5 and 6		35	ns	
t _{en1}	Enable time, A to B		See Figures	3 and 4		65	ns	
t _{en2}	Enable time, B to A		See Figures	5 and 6		65	ns	
ten(TX)	Enable time, receive-to-transmit		See Figure 7			142	ns	

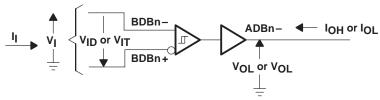
[†] Part-to-part skew is the magnitude of the difference in propagation delay times between any two devices when both operate with the same supply voltages, the same temperature, and the same loads.

[‡] Pulse skew is the difference between the high-to-low and low-to-high propagation delay times of any single channel.



- NOTES: A. Resistance values are in ohms with a tolerance of \pm 5%.
 - B. All input voltage levels are held to within 0.01 V.
 - C. The logical function is set with SDB at 0.8 V, DRVBUS at 3.5 V, and all others left open.

Figure 1. Differential Driver V_{OD} , V_{OH} , and V_{OL} Test Circuit

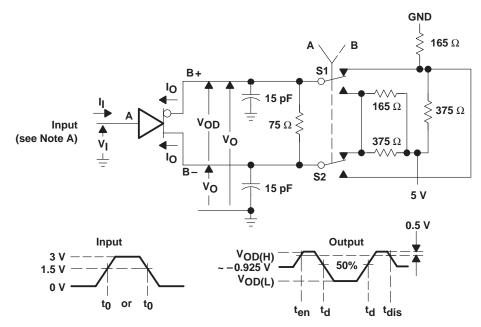


NOTES: A. Resistance values are in ohms with a tolerance of \pm 5%.

- B. All input voltage levels are held to within 0.01 V.
- C. The logical function is set with SDB and DRVBUS at 3.5 V, and all others left open.

Figure 2. Single-Ended Driver V_{OH} , V_{OL} , V_{IT+} , and V_{IT-} Test Circuit





NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 45% < duty cycle < 50%, $t_\Gamma \leq$ 1 ns, $t_f \leq$ 1 n

- B. C_L includes probe and jig capacitance.
- C. Resistance values are in ohms with a tolerance of \pm 5%.
- D. All input voltage levels are held to within 0.01 V.

Figure 3. A to B Propagation Delay Time Test Circuit

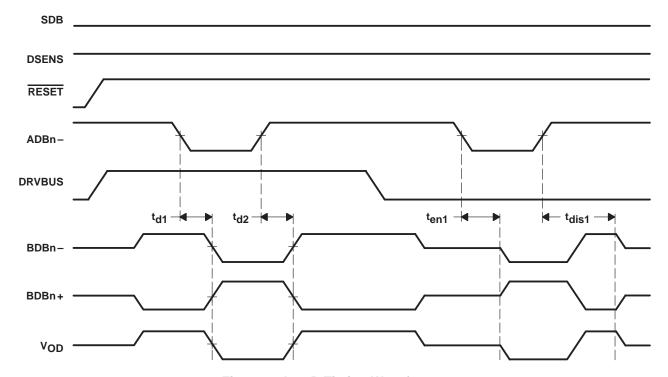
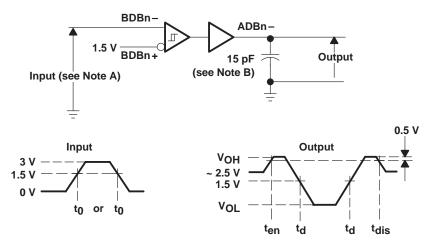


Figure 4. A to B Timing Waveforms





- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR \leq 1 MHz, 45% < duty cycle < 50%, $t_f \leq$ 1 ns, $t_f \leq$ 1 n
 - B. C_L includes probe and jig capacitance.
 - C. Resistance values are in ohms with a tolerance of \pm 5%.
 - D. All input voltage levels are held to within 0.01 V.

Figure 5. B to A Propagation Delay Time Test Circuit

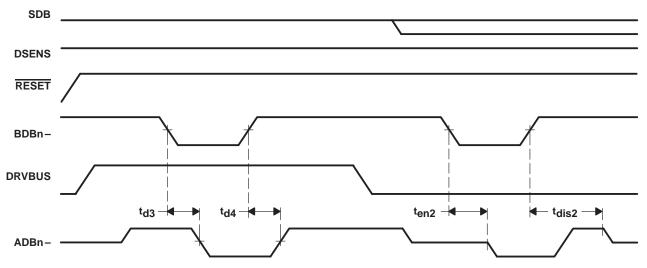


Figure 6. B to A Timing Waveforms

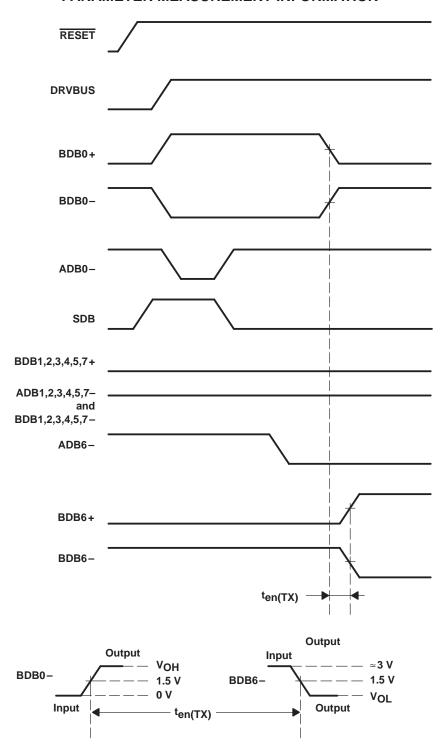
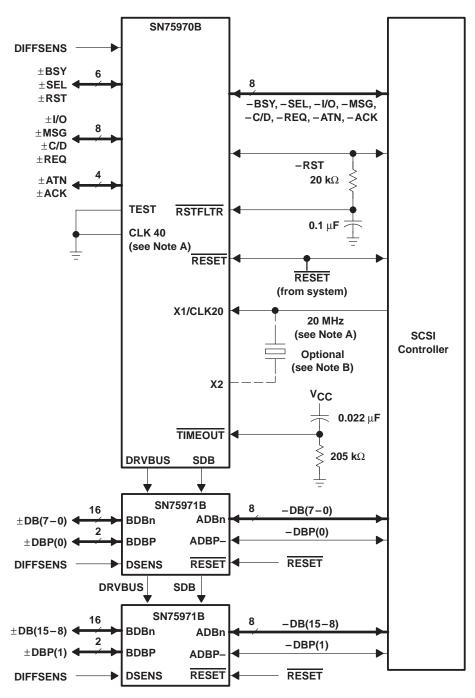


Figure 7. Receive-to-Transmit ($t_{en(TX)}$) Timing Waveforms

APPLICATION INFORMATION



NOTES: A. When using the 40-MHz clock input, X1 must be connected to V_{CC}.

B. The oscillator cell of the SN75970B is for a series-resonant crystal and requires approximately 10 pF (including fixture capacitance) from X1 and X2 to ground in order to function.

Figure 8. Typical Application of the SN75970B and SN75971B

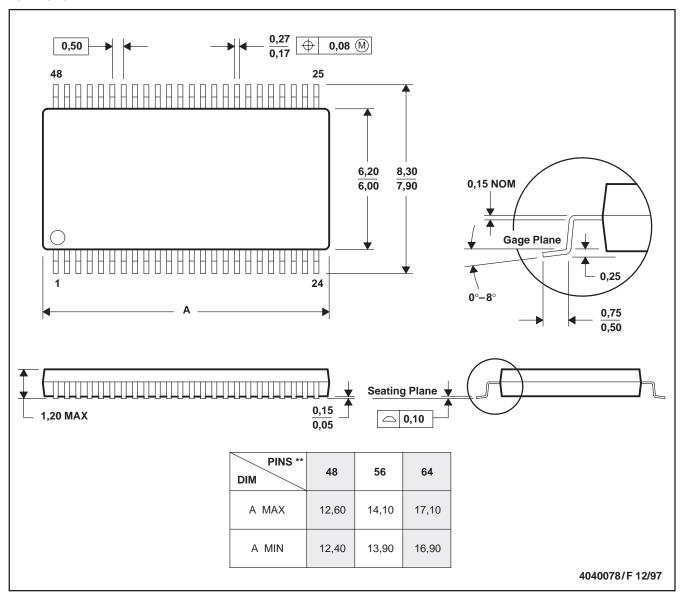


MECHANICAL INFORMATION

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PIN SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

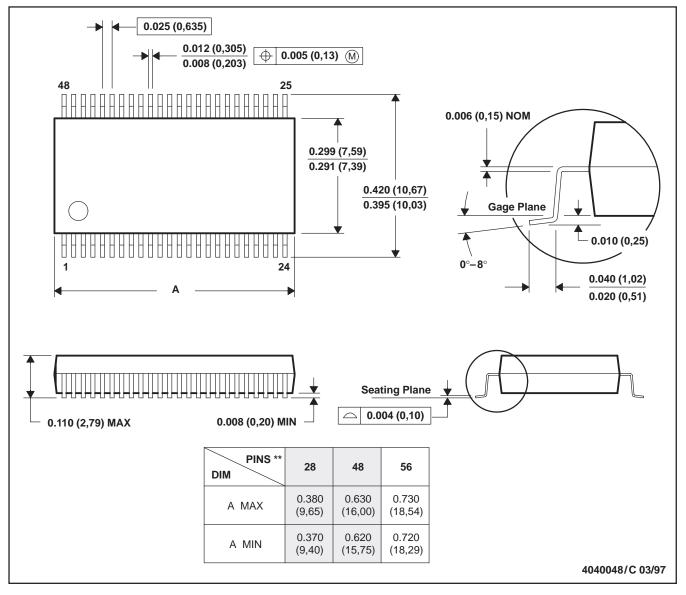
D. Falls within JEDEC MO-153

MECHANICAL INFORMATION

DL (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PIN SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118



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